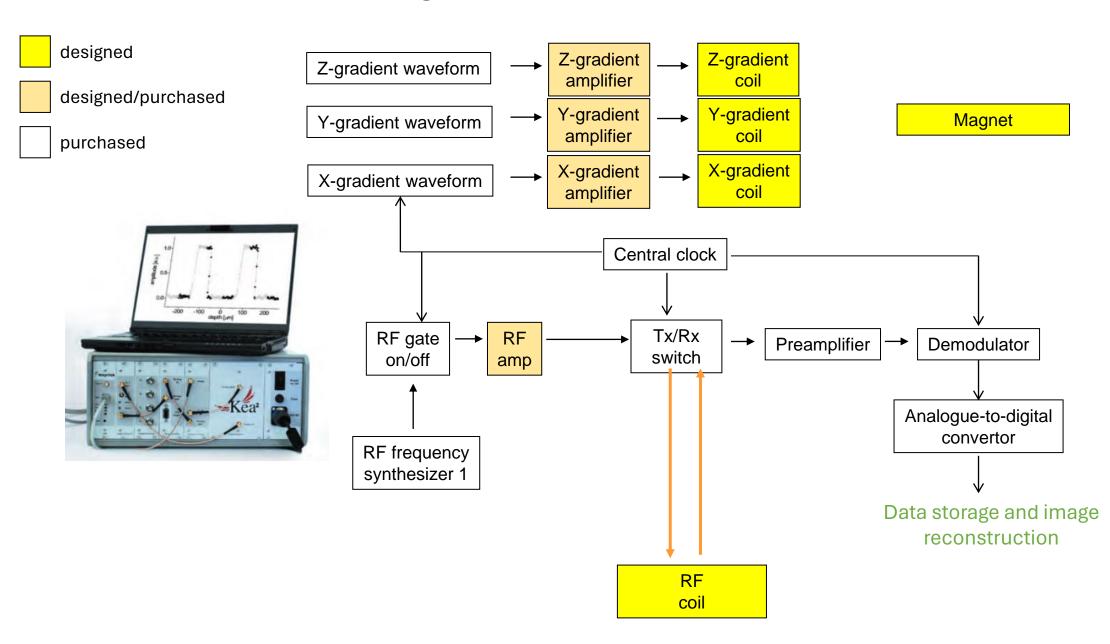
# **System Integration**

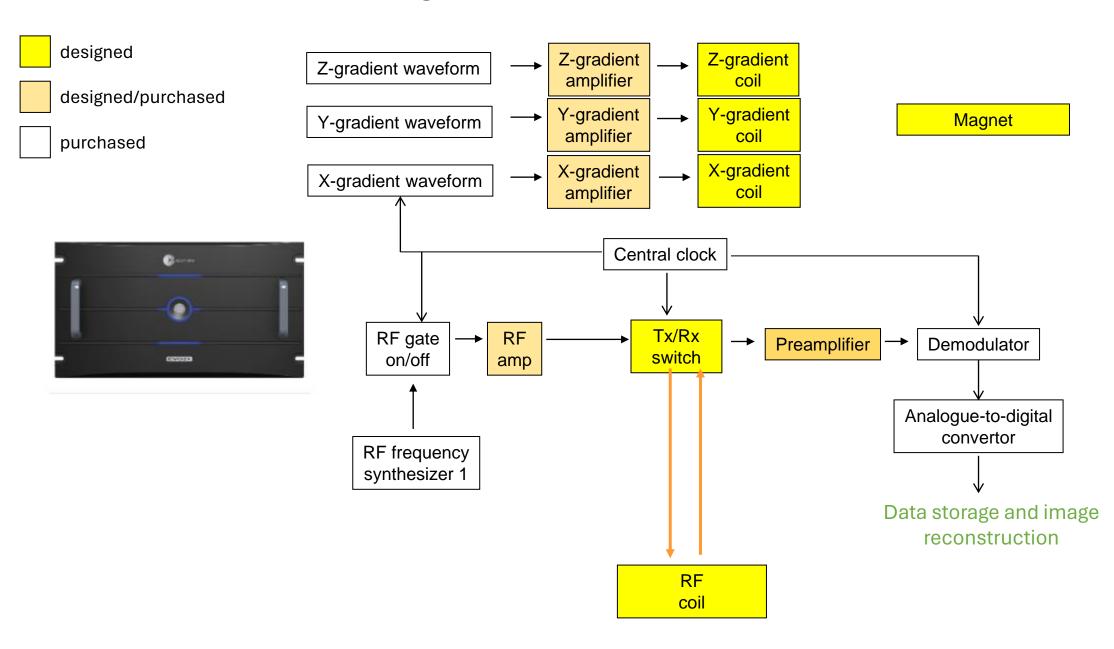
Part 1. Integrated system design

Part 2. Integrating individual components of the system

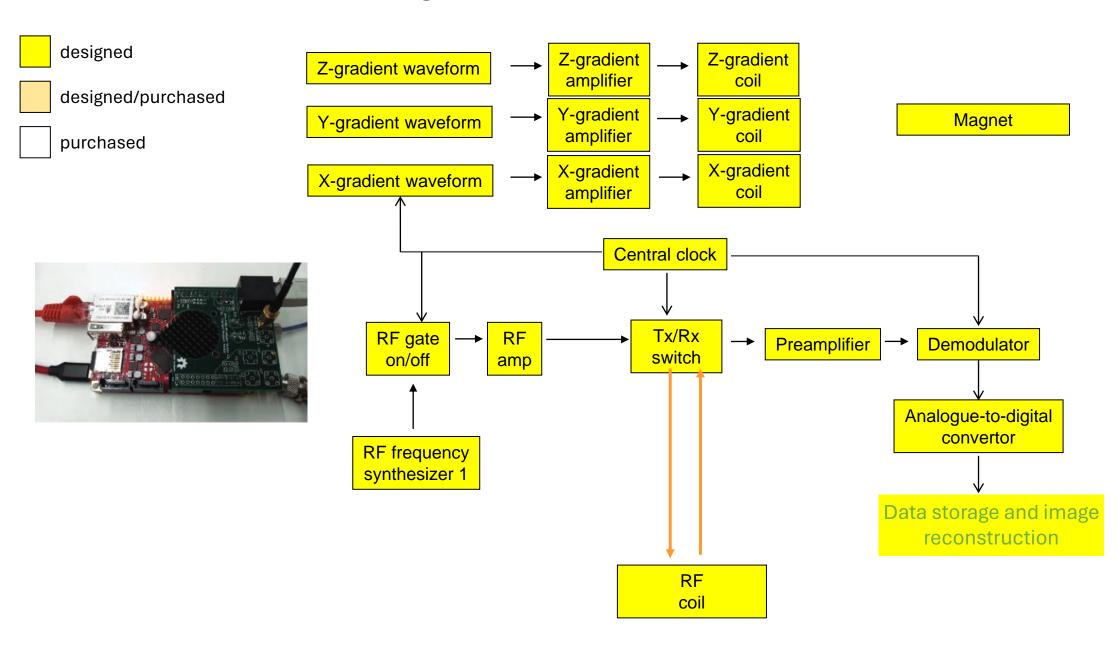
# Overall hardware block diagram I



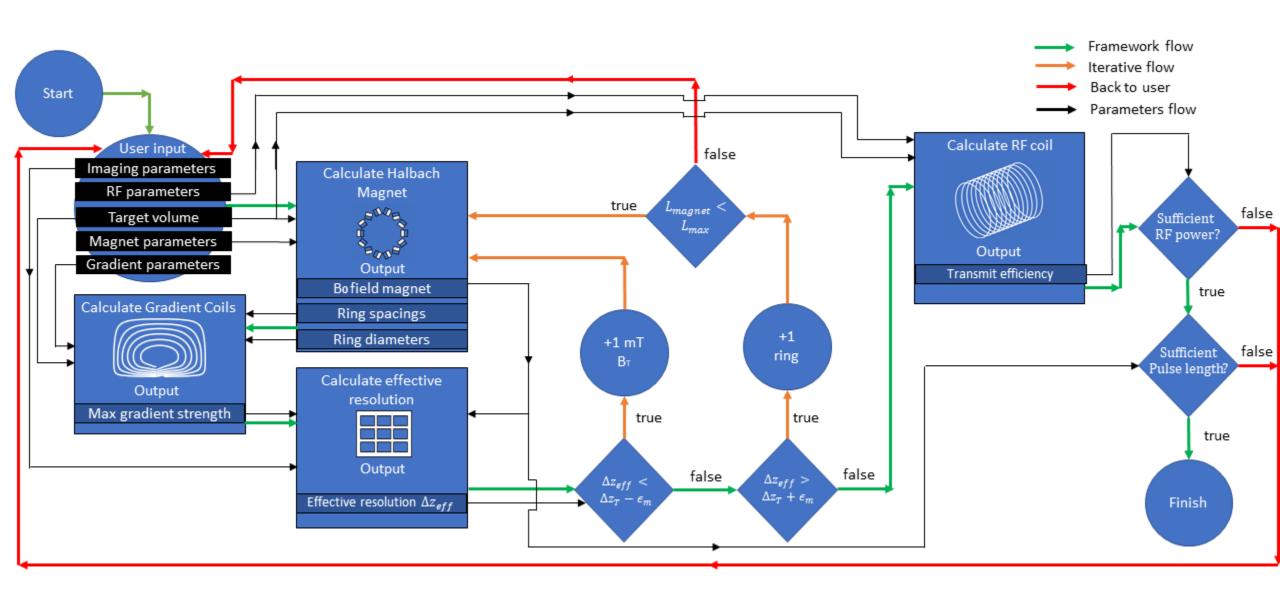
# Overall hardware block diagram II

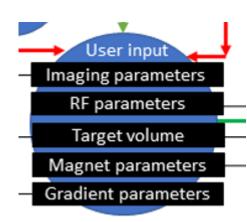


# Overall hardware block diagram III



Part 1. Integrated system design





## Neuroimaging system

Imaging field of view: cylinder length 200 x 200 x 200 mm<sup>3</sup>

Need a spatial resolution of 3 x 3 x 3 mm

Estimate that we want a magnetic field strength of at least 45 mT

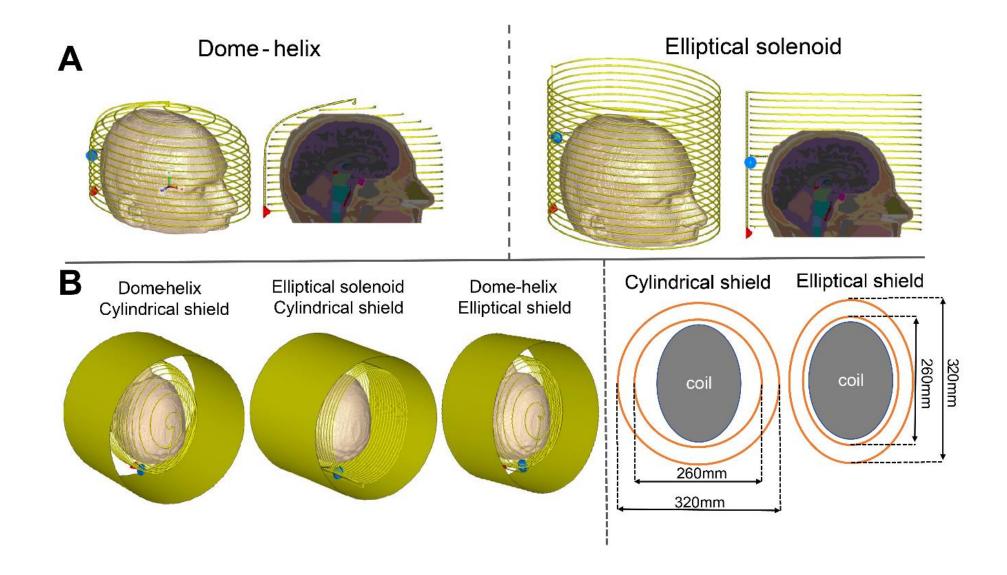
Maximum length of the magnet is 500 mm to position the brain at the centre

So the RF coil is specified as cylinder 240 x 240 x 240 mm

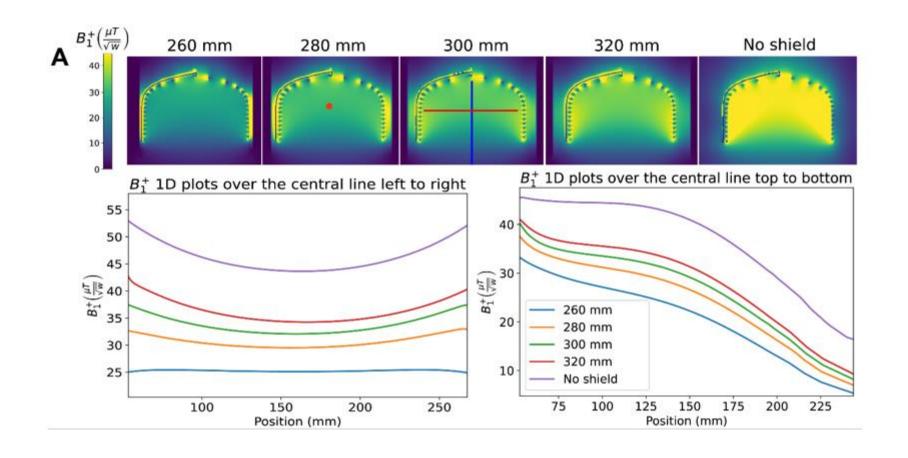
Gradient coil length set at 500 mm

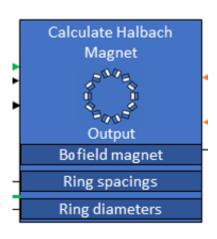
Diameter 300 mm (to avoid reducing Tx/Rx efficiency)

### **Effect of RF shield on RF coil performance**



#### Decrease in SNR as function of shield-to-coil distance



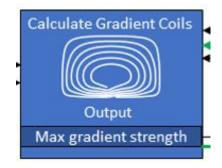


# Optimization via many different methods

Most methods model individual magnets as dipoles

Start with a reasonable guess in terms of diameter, length, number of rings based on previous designs (although not critical)

In this case, 25 rings, 20 mm in-between rings



#### Can use different approaches, target field, boundary element methods etc......

### Gradient design algorithm:

- 1. Initialization:
  - a. Obtain gradient coil length and radius from magnet dimensions
  - b. Specify target gradient field vector **k**
  - Specify the wire thickness, and minimum wire spacing
  - d. Specify maximum linearity
- Find expansion coefficients ~ for a range of the regularization parameter λ
- 3. Determine gradient efficiencies and linearities for all values of  $\lambda$
- 4. Find most efficiency coil corresponding to the maximum allowable linearity error.

# Calculate effective resolution Output Effective resolution Δz<sub>eff</sub>

#### Consider the effect of B<sub>0</sub> inhomogeneity and gradient strength (bandwidth)

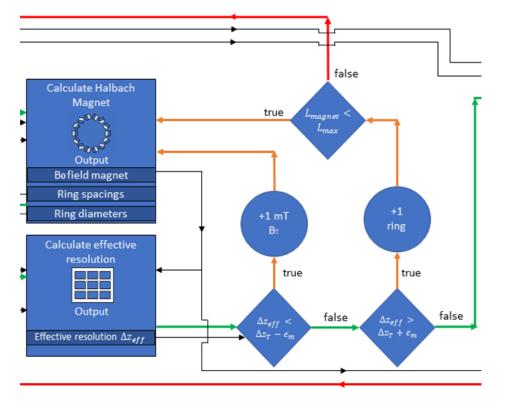
$$\frac{1}{T_2^*} = \frac{1}{T_2} + \gamma \Delta B_0$$

$$\gamma \Delta B_0 \gg \frac{1}{T_2} \qquad T_2^* \approx \frac{1}{\gamma \Delta B_0}$$

BW = FOV x gradient strength

$$\Delta z_{eff} = N_z \Delta z \frac{\tanh\left(\frac{\pi \text{FWHM}}{2BW}\right)}{1 - e^{-\frac{\pi \text{FWHM}N_z}{2BW}}}$$

where BW is the maximum obtainable readout bandwidth of the gradient system determined with the least efficient gradient,  $\Delta z$  the digital resolution and  $N_z$  the number of points.



#### **Iterative loop**

FOV 200 x 200 x 200, spatial resolution 3 x 3 x 3 Data matrix: 80 x 66 x 66 assuming 0.5 mm frequency encoding blurring

Magnet: 25 rings, 20 mm ring spacing
Optimization of spacing and diameter gives 4329 ppm
Gradient coils: optimization gives an X-gradient with efficiency
0.24 mT/m/A. Maximum 30 Amps gives an effective spatial
resolution of ~10 mm.



Magnet: add one ring to increase  $B_0$  homogeneity Optimization of spacing and diameter gives 1075 ppm Gradient length increases, 0.26 mT/m/A, resolution ~4.1 mm



Magnet: add one ring to increase B0 homogeneity Optimization of spacing and diameter gives 381 ppm Gradient length increases, resolution ~2.6 mm

Magnet: increase target B0 in 1 mT steps Change length and diameter, while Maintaining target resolution



# Output Transmit efficiency Sufficient RF power? true Sufficient Pulse length?

#### Check that the RF side is adequate

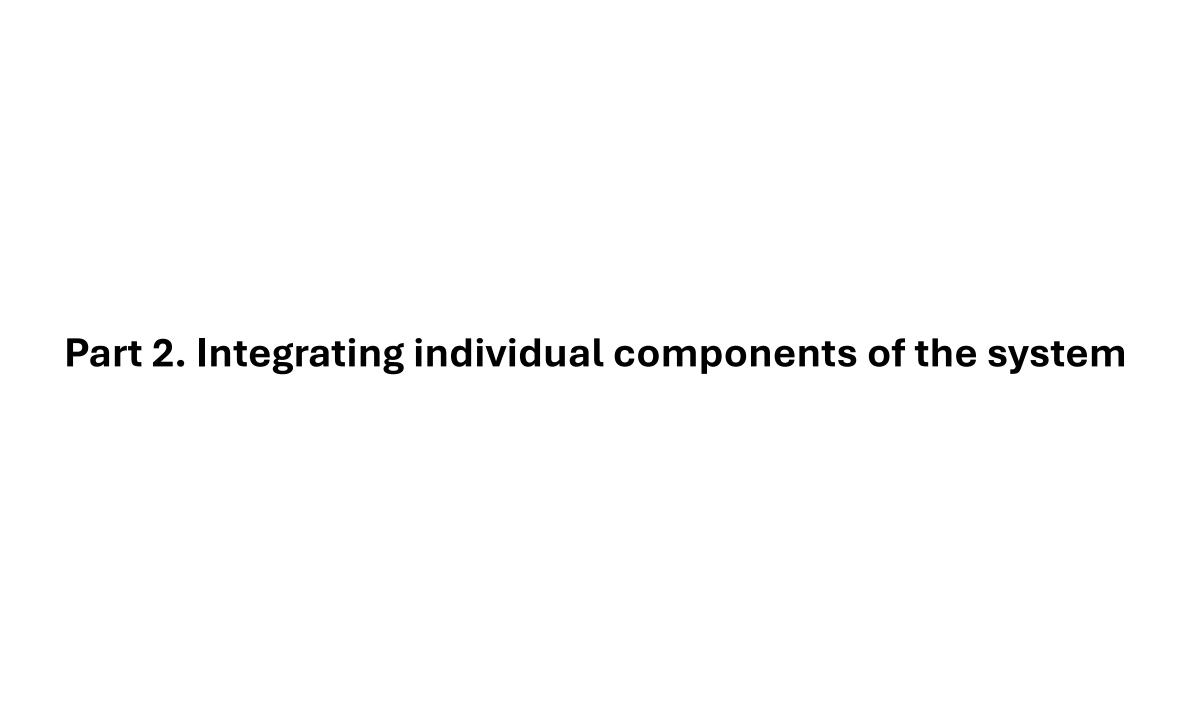
Solenoid: 240 x 240 x 240 mm

B<sub>1</sub> uniformity > 20%

Transmit efficiency 26 microTesla per √Watt input power

1 milleWatt maximum output power of spectrometer RF amplifier gain 54 dB Maximum flip angle 180° Pulse duration 50 microseconds

Maximum output power is 9 Watts RF pulse excites bandwidth of ~20 kHz which is greater than  $\Delta B_0$ 



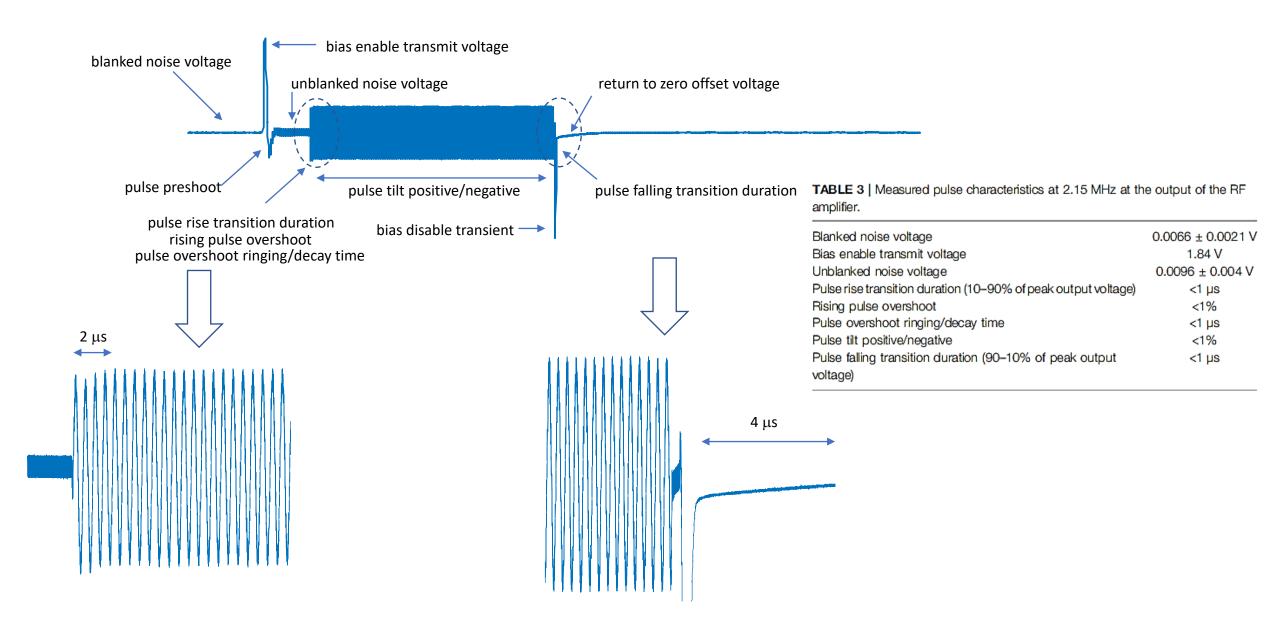
# RF amplifier

What is maximum input to RF amplifier?

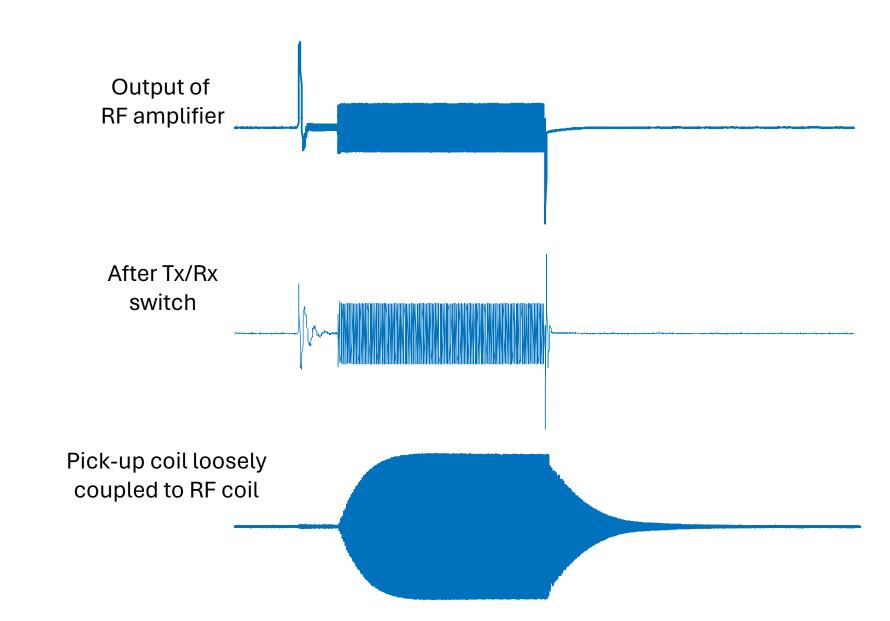
What is the maximum duty cycle/pulse length the amplifier can deal with? What is the shortest pulse that it can amplify? What is the dynamic range of the amplifier (soft pulses)? How much reflected power can it take? RF Tx/Rx RF gate RF frequency switch synthesizer 1  $50 \Omega$  $50 \Omega$ on/off amp RG58 cable RG58 cable spectrometer  $50 \Omega$ RG58 cable RF coil

Assume that we have an RF coil that is impedance matched at ~50 Ohms

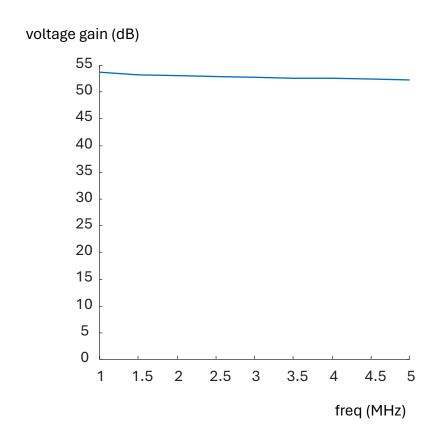
#### **Characterizing the RF amplifier performance**

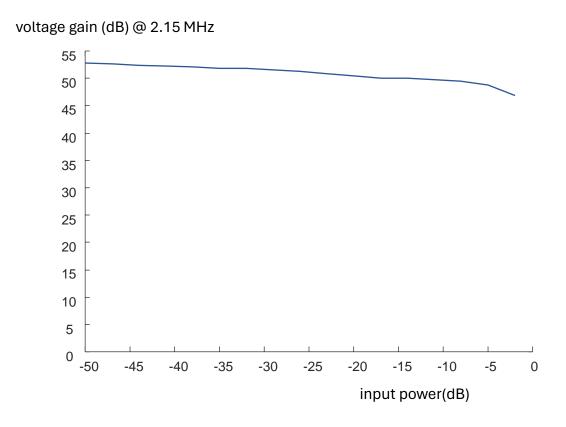


# Characterizing the RF amplifier performance

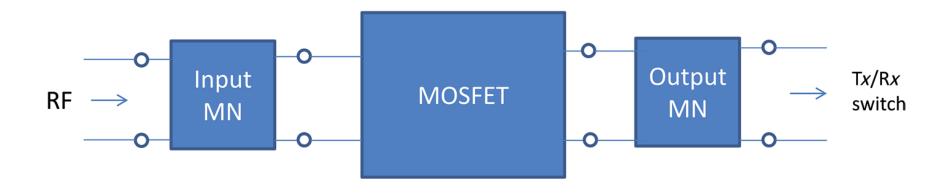


### Characterizing the RF amplifier performance





# Looking inside the RF amplifier



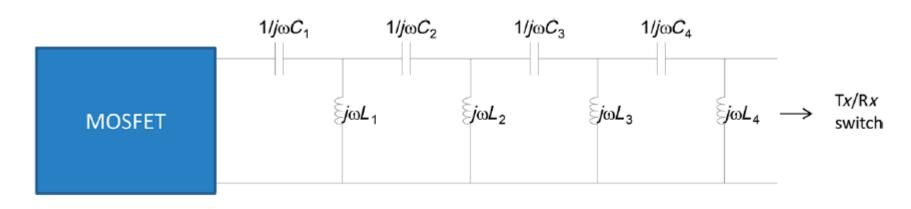
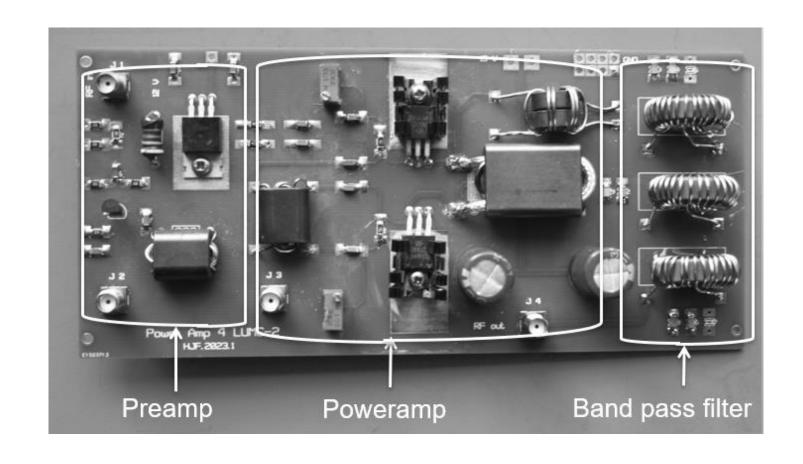
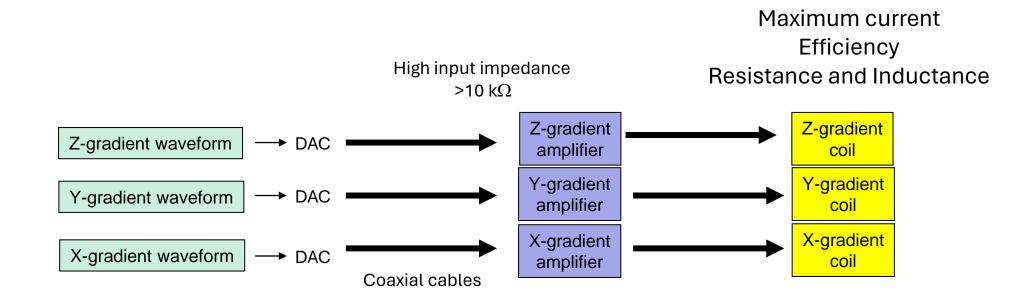


Figure 6.17 Schematic of a broadband matching network.

# Design of a simple ~10 Watt output amplifier



Gradient amplifier



#### Simple gradient coil characteristics

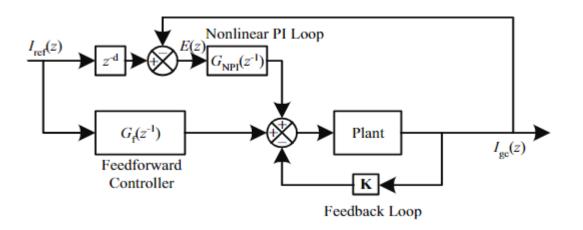
Gradient coil has a resistance, inductance (L), capacitance C from the different turns, frequency dependent inductive reactance ( $\omega$ L), and frequency dependent capacitive reactance ( $1/\omega$ C)

So there is a resonant frequency (or several resonant frequencies) from the gradient coils which we have To be aware of since they typically occur in the ~MHz range, good shielding between gradients and RF is required Otherwise they will couple together VERY strongly.

The impedance of the gradient coils is frequency dependent, so their characteristics depend on whether the gradient is being turned on (high frequency components) or is in steady-state (very low frequency)

Typical numbers: inductance 200 microhenries, resistance 0.4 Ohms. At 1 kHz,  $\omega$ L=1.2 Ohms, at 10 kHz  $\omega$ L=12 Ohms. So complex impedance is 0.4+j1.2 or 0.4+j12

Feedforward and feedback controller for "correcting" the gradient waveform



When running a constant-current control loop that drives a voltage across an inductive load, the load's impedance directly affects the control loop response and stability, and so to be able to make the amplifier work well with a variety of gradient coils (a range of both load inductances and resistances), the control loop values need to be adjusted.

#### Technical Data Draft

#### **Gradient Amplifier GA-30-15**

Part-No. 410000

Output Channels 1

Output Current  $\pm$  30 A peak /  $\pm$  20 A average

Output Williage 1 15 V

Load Impedance 0.1-4.8 Ohms

o-20 mHenry

Digital Resolution 16 bit internal DAC / 1 mA steps

Input Voltage for channel 0  $\pm$  10 V



#### System specifications

Supply voltage 100 – 400 Vdc Input current max 30 A

Load inductance 30 uH – 5 mH

Environmental requirements:

Load resistance

Ambient temperature 10 °C to 40 °C

Ambient humidity 30 to 75 % non-condensing

0 Ω - 1 Ω

Transport temperature -25 °C to +60 °C

Cooling Air cooling (front in, rear out)



3-Axis MRI Gradient Amplifier

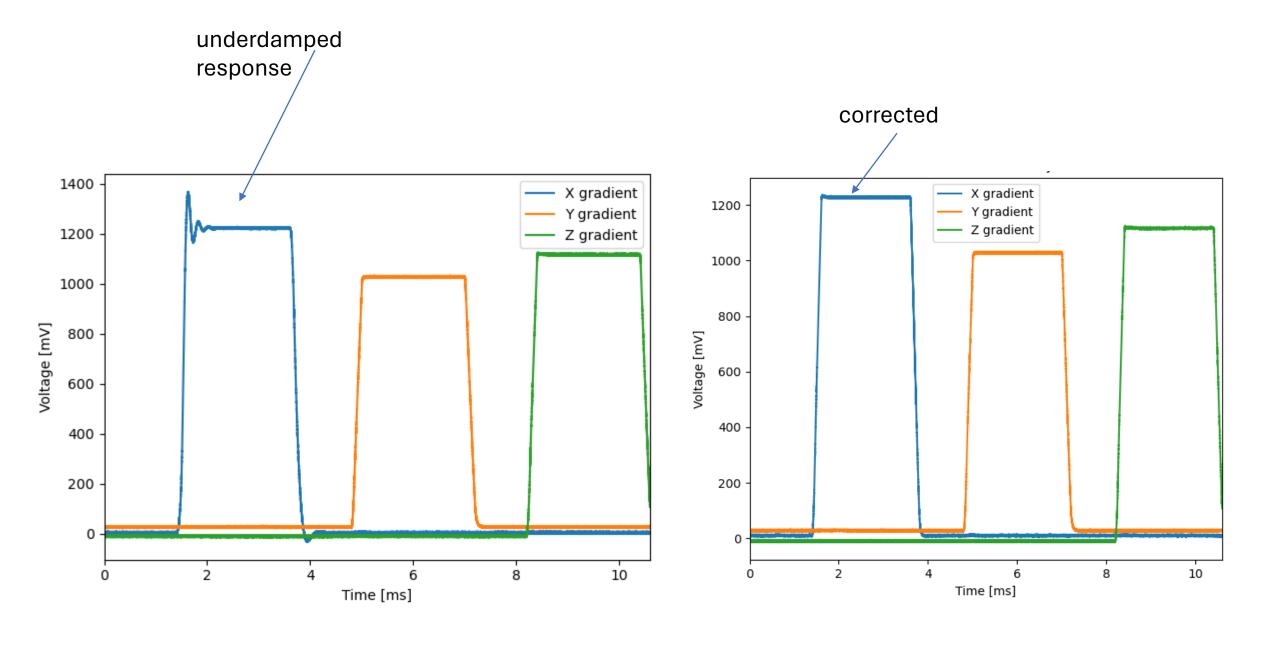
175A 350V

Rise time of the gradient coils for a step input function is given by L/R



Match the DC resistance of gradient coil to designed load resistance of the amplifier achieves maximum continuous gradient.

Reducing the impedance of the gradient coil decreases the rise time, but reduces peak gradient



# Illustrative examples of passive "impedance matching" for a Bruker amplifier

Table 7.1. Micro5 Probe and Gradient Specifications

Gradients	XYZ
Gradient strength	4.8 G/cm/A
ID/OD	19/40 mm
Linearity +-1.3% peak-peak +- 1.6% peak-peak +- 2.1% peak-peak	18 mm sphere 19 mm sphere 20 mm sphere
Inductance	10 - 20 μΗ
Resistance	=< 120 mΩ
Rise time, 0-40A, 120V	< 50 μs
Cooling	air or water
Maximum current tested	40 A

Table 7.2. B-AFPA-40 Dip Switch Setting

Gradient system	Gradient	C Dip Switch	R Dip Switch	С	R
Micro5	X	0000 1000	0001 0000	1.5 nF	20 kΩ
Micro5	Υ	0000 0100	0001 0000	1.0 nF	20 kΩ
Micro5	Z	0000 1000	0000 1000	1.5 nF	15 kΩ

Table 7.4. Micro2.5 probe and gradient specifications

Gradients	XYZ
Gradient strength	2.5 G/cm/A
ID/OD	40/72 mm
Linearity +-1.8% peak-peak +- 2.2% peak-peak +- 3.0% peak-peak	36 mm sphere 38 mm sphere 40 mm sphere
Inductance	=< 100 μH
Resistance	=< 400 mΩ
Rise time, 0-40A, 120V	< 110 μs
Cooling	air or water
Maximum current tested	40 A

Gradient system	Gradient	C Dip Switch	R Dip Switch	С	R
Micro2.5	Х	00001100	00010000	2.5 nF	20 kΩ
Micro2.5	Υ	00001100	00010000	2.5 nF	20 kΩ
Micro2.5	Z	00001100	00010000	2.5 nF	20 kΩ

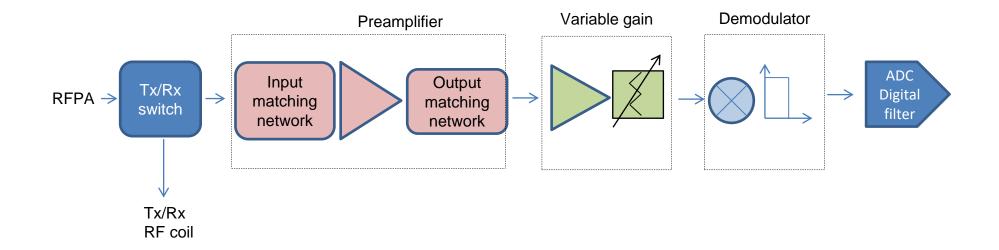
Table 7.8. Mini05 Probe and Gradient Specifications

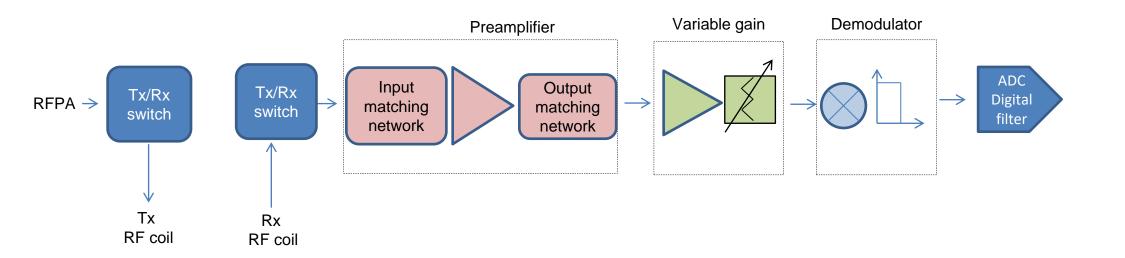
gradients	XYZ
gradient strength	0.5 G/cm/A
ID/OD	57/72 mm
linearity +-2% peak-peak, Z / XY +- 10% peak-peak, Z / XY	30 / 43 mm 40 / 52 mm
inductance	=< 70 μH
resistance	=< 1.6 Ω
rise time, 0-40A, 120V	< 150 μs
cooling	water
maximum current tested	50 A

Table 7.9. B-AFPA-40 Dip Switch Setting

Gradient system	Gradient	C Dip Switch	R Dip Switch	С	R
Mini0.5	X	0001 1100	0000 1000	4.7 nF	15 kΩ
Mini0.5	Υ	0001 0000	0000 1000	2.2 nF	15 kΩ
Mini0.5	Z	0001 0000	0001 0000	2.2 nF	20 kΩ

# Receiver

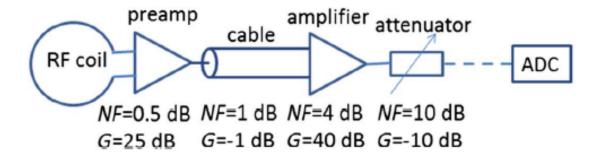


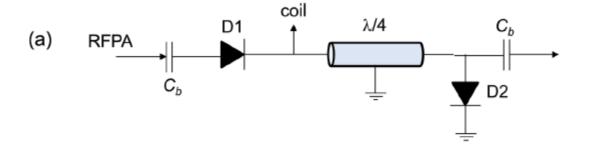


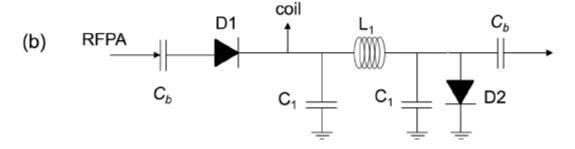
#### Performance of each element in the receiver chain

$$NF_{\text{total}} = NF_{\text{preamp}} + \frac{\left(NF_{\text{cable}} - 1\right)}{G_{\text{preamp}}} + \frac{NF_{\text{amp}}}{G_{\text{preamp}}G_{\text{cable}}} + \frac{NF_{\text{attenator}}}{G_{\text{preamp}}G_{\text{cable}}G_{\text{amp}}}$$
(7.4)

Using the numbers in Figure 7.3, the overall NF is 0.51 dB, which is very close to the NF of the first-stage amplifier. Indeed, eqn (7.4) shows that the critical component in terms of the overall NF of the receiver is the first stage,







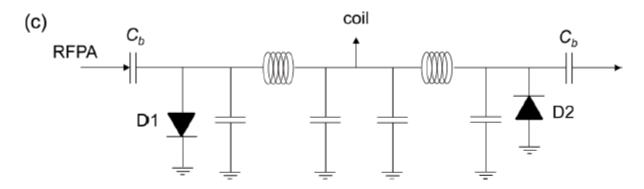
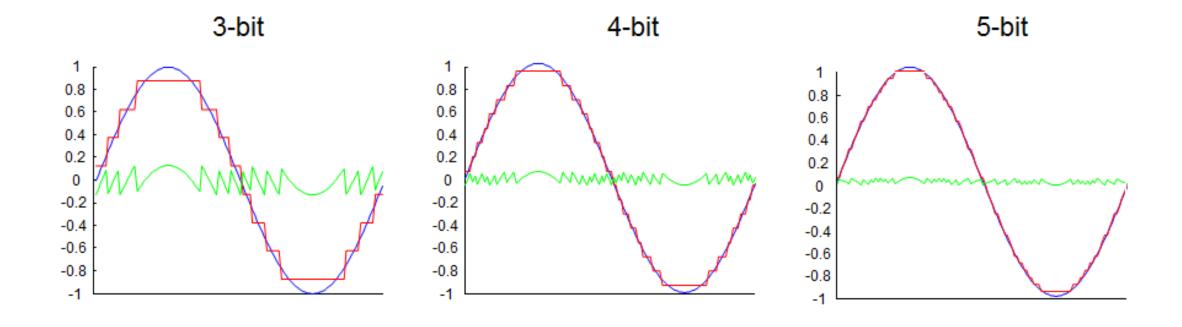
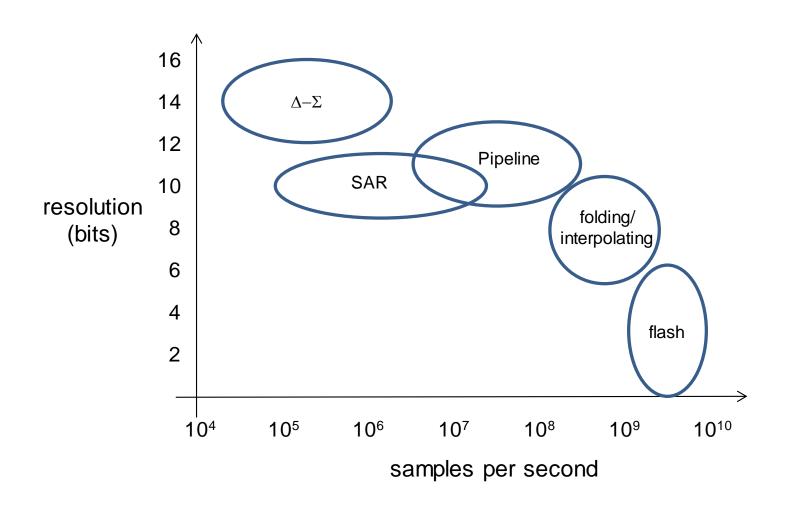


Figure 7.4 Three variations of T/R switch based on a quarter-wavelength transmission line (a) and its lumped element pi-section equivalent (b) and (c). In (c) two pi-sections are used for additional isolation between transmitter and receiver. Capacitors C<sub>b</sub> are very high value to provide a DC-block for the diode-driving voltage, and present essentially a short circuit at RF frequencies.

# Resolution of analogue-to-digital converters



# Analogue-to-digital converters



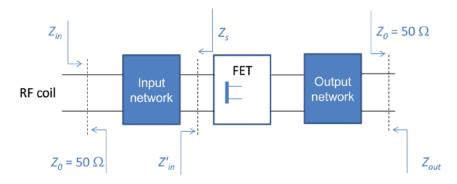
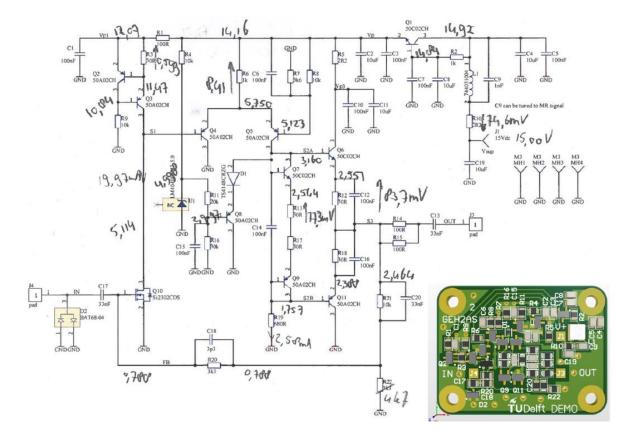


Figure 7.7 Block diagram of a FET-based preamplifier connected on the input side to an RF coil impedance matched to 50  $\Omega$ , and on the output side to a 50  $\Omega$  cable.



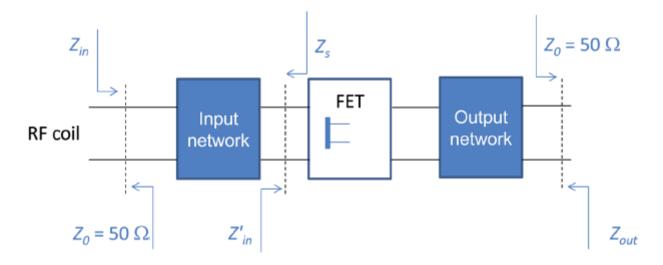
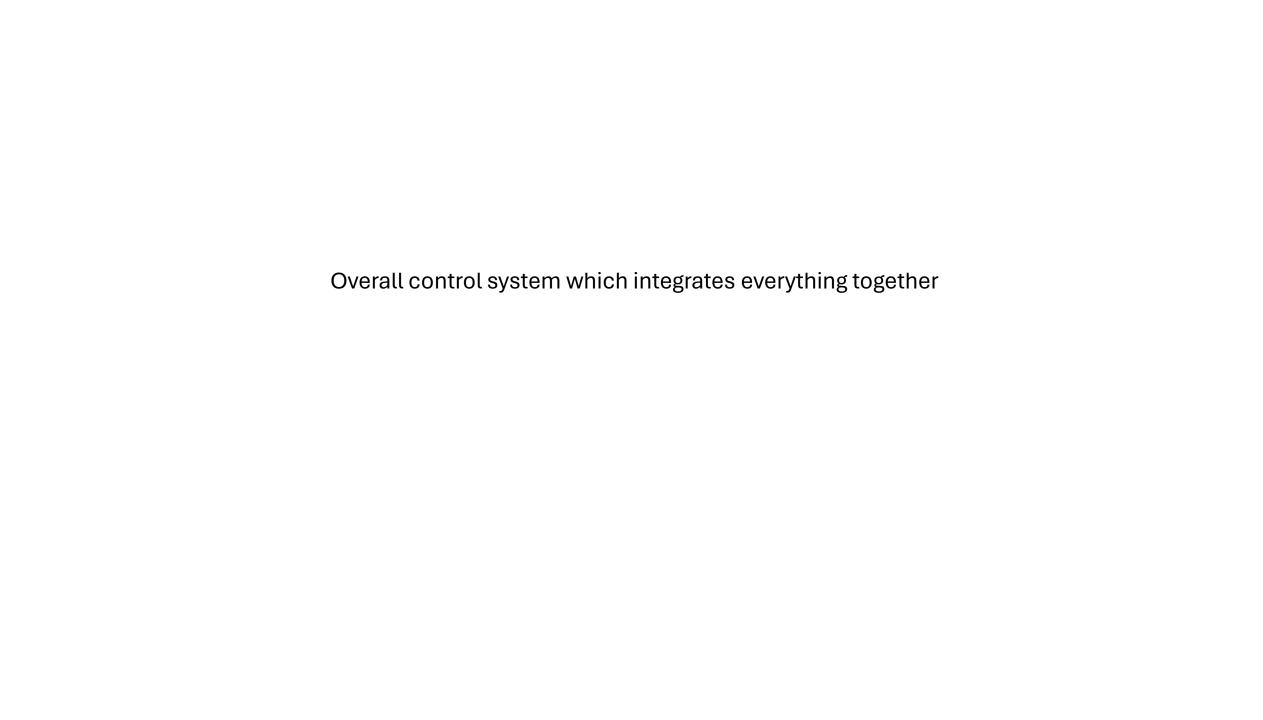
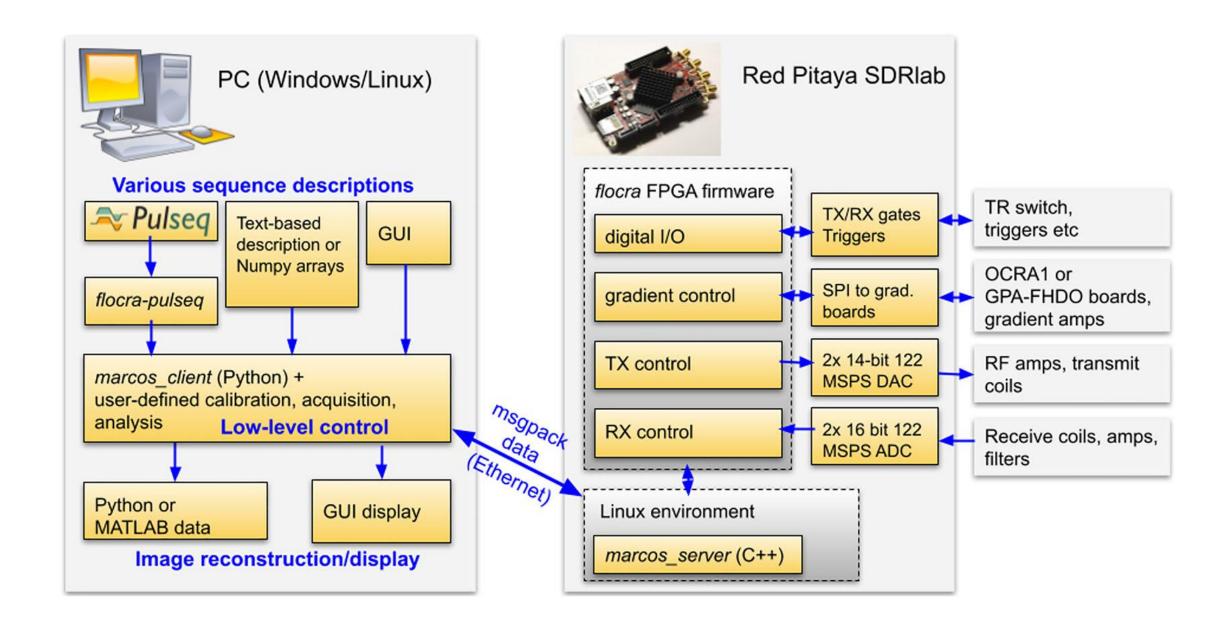
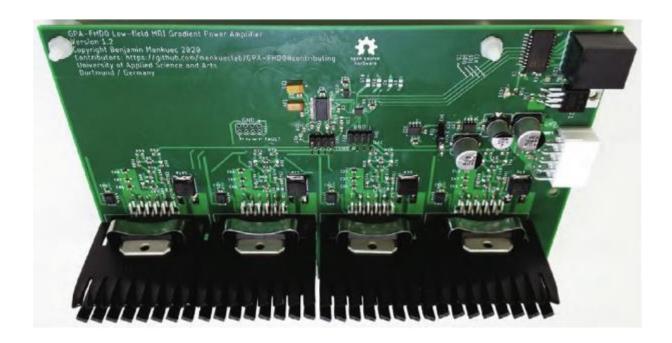


Figure 7.7 Block diagram of a FET-based preamplifier connected on the input side to an RF coil impedance matched to 50  $\Omega$ , and on the output side to a 50  $\Omega$  cable.





#### Interface with gradient amplifier (optional) and gradient coils



Four channel gradient 16 bit DAC board

Internal power stage which can delivers +/- 10 Amps on each channel

Can also output +/- 12 volts output for external gradient power amplifier

Clock speed 40 MHz – so if all 4 channels are used in parallel, clocks at 100,000 samples per second, so 10 microseconds per sample

Current is continuously monitored which can be used to calibrate the system.





Compact and mobile scanners are changing workflows in radiology, where MRI comes to the patient rather than the patient to the MRI. In this project we will establish the necessary metrological framework for the harmonised development of clinical low-field MRI.

Read more

